DDA (LO-R1) H

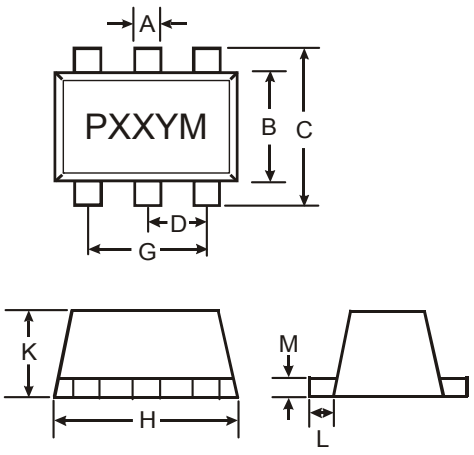
PNP PRE-BIASED SMALL SIGNAL DUAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDC)
- Built-In Biasing Resistors
- **Lead Free By Design/RoHS Compliant (Note 3)**
- **"Green" Device (Note 4 and 5)**

Mechanical Data

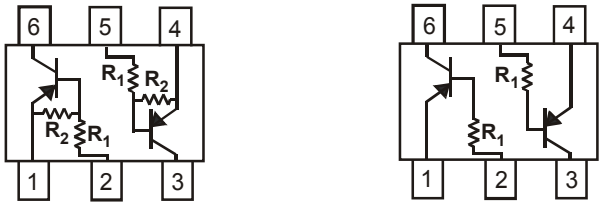
- Case: SOT-563
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish - Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.005 grams (approximate)



SEE NOTE 1

SOT-563			
Dim	**Min**	**Max**	**Typ**
A	0.15	0.30	0.25
B	1.10	1.25	1.20
C	1.55	1.70	1.60
D		0.50	
G	0.90	1.10	1.00
H	1.50	1.70	1.60
K	0.56	0.60	0.60
L	0.15	0.25	0.20
M	0.10	0.18	0.11
All Dimensions in mm			

P/N	R1 (NOM)	R2 (NOM)	MARKING
DDA122LH	0.22KΩ	10KΩ	P81
DDA142JH	0.47KΩ	10KΩ	P82
DDA122TH	0.22KΩ	OPEN	P83
DDA142TH	0.47KΩ	OPEN	P84



R_1, R_2 R_1 Only

SCHEMATIC DIAGRAM, TOP VIEW

Maximum Ratings

@T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Supply Voltage (6) to (1) and (3) to (4)		V_{CC}	-50	V
Input Voltage (2) to (1) and (5) to (4)	DDA122LH DDA142JH	V_{IN}	+5 to -6 +5 to -6	V
Input Voltage (1) to (2) and (4) to (5)	DDA122TH DDA142TH	$V_{EBO\ (MAX)}$	-5	V
Output Current	All	I_C	-100	mA
Power Dissipation		P_d	150	mW
Thermal Resistance, Junction to Ambient Air	(Note 2)	$R_{\theta JA}$	833	°C/W
Operating and Storage Temperature Range		T_j, T_{STG}	-55 to +150	°C

Notes:
1. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).
2. Mounted on FR4 Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.
3. No purposefully added lead.
4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

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Electrical Characteristics @T_A = 25°C unless otherwise specified **R1, R2 Types**

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDA122LH DDA142JH	$V_{I(off)}$	-0.3 -0.3	—	—	V	V_{CC} = -5V, I_O = -100μA
	DDA122LH DDA142JH	$V_{I(on)}$	—	—	-2.0 -2.0	V	V_O = -0.3V, I_O = -20mA V_O = -0.3V, I_O = -20mA
Output Voltage		$V_{O(on)}$	—	—	-0.3V	V	I_O/I_I = -5mA/-0.25mA
Input Current	DDA122LH DDA142JH	I_I	—	—	-28 -13	mA	V_I = -5V
Output Current		$I_{O(off)}$	—	—	-0.5	μA	V_{CC} = -50V, V_I = 0V
DC Current Gain	DDA122LH DDA142JH	G_I	56 56	—	—	—	V_O = -5V, I_O = -10mA
Gain-Bandwidth Product*		f_T	—	200	—	MHz	V_{CE} = -10V, I_E = -5mA, f = 100MHz

* Transistor - For Reference Only

Electrical Characteristics @T_A = 25°C unless otherwise specified **R1-Only**

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV_{CBO}	-50	—	—	V	I_C = -50μA
Collector-Emitter Breakdown Voltage		BV_{CEO}	-40	—	—	V	I_C = -1mA
Emitter-Base Breakdown Voltage	DDA122TH DDA142TH	BV_{EBO}	-5	—	—	V	I_E = -50μA I_E = -50μA
Collector Cutoff Current		I_{CBO}	—	—	-0.5	μA	V_{CB} = -50V
Emitter Cutoff Current	DDA122TH DDA142TH	I_{EBO}	— —	—	-0.5 -0.5	μA	V_{EB} = -4V
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	—	—	-0.3	V	I_C = -5mA, I_B = -0.25mA
DC Current Transfer Ratio	DDA122TH DDA142TH	h_{FE}	100 100	250 250	600 600	—	I_C = -1mA, V_{CE} = -5V
Gain-Bandwidth Product*		f_T	—	200	—	MHz	V_{CE} = -10V, I_E = 5mA, f = 100MHz

* Transistor - For Reference Only

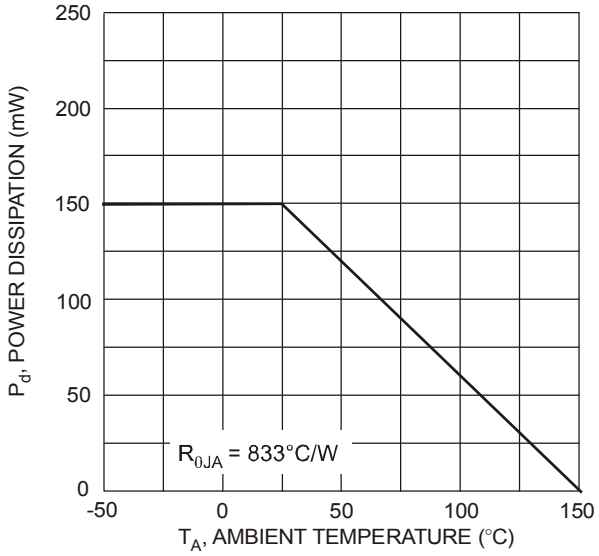

Fig. 1 Power Derating Curve

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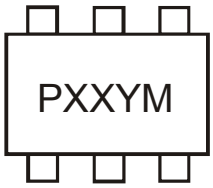
Ordering Information (Note 6)

Device	Packaging	Shipping
DDA122LH-7	SOT-563	3000/Tape & Reel
DDA142JH-7	SOT-563	3000/Tape & Reel
DDA122TH-7	SOT-563	3000/Tape & Reel
DDA142TH-7	SOT-563	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XXX = Product Type Marking Code (See Page 1)
YM = Date Code Marking
Y = Year ex: T = 2006
M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	N	P	R	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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